

P-Channel Enhancement Mode MOSFET

Feature

- -40V/-90A
 - $R_{DS(ON)} = 5.6$ @VGS = -10V
 - $R_{DS(ON)} = 8.8$ @VGS = -4.5V
- 100% Avalanche Tested
- 100% DVDS
- MSL1 up to 260 Peak Reflow
- AEC-Q101 Qualified
- 175 operating temperature
- Reliable and Rugged
- Halogen Free and Green Devices Available (RoHS Compliant)

Pin Description

G D S
G D S

G D S

Applications

- Switching application
- Li-battery protection
- Motor control

Single P-

Ordering and Marking Information

<table style="width: 100%; text-align: center;"> <tr> <td style="width: 33%;"> <div style="display: flex; justify-content: space-around; align-items: center;"> <div style="width: 20px; height: 20px; background-color: black; margin-bottom: 5px;"></div> D </div> <p>HYA060P04 XYMXXXXXX</p> </td> <td style="width: 33%;"> <div style="display: flex; justify-content: space-around; align-items: center;"> <div style="width: 20px; height: 20px; background-color: black; margin-bottom: 5px;"></div> U </div> <p>HYA060P04 XYMXXXXXX</p> </td> <td style="width: 33%;"> <div style="display: flex; justify-content: space-around; align-items: center;"> V </div> <p>HYA060P04 XYMXXXXXX</p> </td> </tr> </table>	<div style="display: flex; justify-content: space-around; align-items: center;"> <div style="width: 20px; height: 20px; background-color: black; margin-bottom: 5px;"></div> D </div> <p>HYA060P04 XYMXXXXXX</p>	<div style="display: flex; justify-content: space-around; align-items: center;"> <div style="width: 20px; height: 20px; background-color: black; margin-bottom: 5px;"></div> U </div> <p>HYA060P04 XYMXXXXXX</p>	<div style="display: flex; justify-content: space-around; align-items: center;"> V </div> <p>HYA060P04 XYMXXXXXX</p>	<p>Package Code D: TO-252-2L U: TO-251-3L V: TO-251-3S</p> <p>Date Code XYMXXXXXX</p>
<div style="display: flex; justify-content: space-around; align-items: center;"> <div style="width: 20px; height: 20px; background-color: black; margin-bottom: 5px;"></div> D </div> <p>HYA060P04 XYMXXXXXX</p>	<div style="display: flex; justify-content: space-around; align-items: center;"> <div style="width: 20px; height: 20px; background-color: black; margin-bottom: 5px;"></div> U </div> <p>HYA060P04 XYMXXXXXX</p>	<div style="display: flex; justify-content: space-around; align-items: center;"> V </div> <p>HYA060P04 XYMXXXXXX</p>		

Note: HUAYI halogen free products contain molding compounds and 100% matte tin plate Termination finish; which are fully compliant with RoHS. HUAYI halogen free products meet or exceed the halogen free requirements of IPC/JEDEC J-STD-020 for MSL classification at halogen free peak reflow temperature. HUAYI defines Green to mean halogen free (RoHS compliant) and halogen free (Br or Cl does not exceed 900ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500ppm by weight).

HUAYI reserves the right to make changes, corrections, enhancements, modifications, and improvements to this product and/or to this document at any time without notice.

Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit	
Common Ratings (Tc=25°C Unless Otherwise Noted)				
V _{DSS}	Drain-Source Voltage	-40	V	
V _{GSS}	Gate-Source Voltage	± 20	V	
T _J	Junction Temperature Range	-55 to 175	°C	
T _{STG}	Storage Temperature Range		°C	
I _S	Source Current-Continuous(Body Diode)	Tc=25°C	-90	A
Mounted on Large Heat Sink				
I _{DM}	Pulsed Drain Current *	Tc=25°C	-270	A
I _D	Continuous Drain Current	Tc=25°C	-90	A
		Tc=100°C	-64	A
P _D	Maximum Power Dissipation	Tc=25°C	122	W
		Tc=100°C	61	W
R _{θJC}	Thermal Resistance, Junction-to-Case		1.23	°C/W
R _{θJA}	Thermal Resistance, Junction-to-Ambient **		75	°C/W
E _{AS}	Single Pulsed-Avalanche Energy ***	L=0.3mH	263	mJ

Note: * Repetitive rating pulse width limited by max.junction temperature.

** Surface mounted on 1in2 FR-4 board.

*** Limited by T_{Jmax}, starting T_J=25°C, L = 0.3mH, R_c= 25

Electrical Characteristics (Cont.) (Tc =25°C Unless Otherwise Noted)

Symbol	Parameter	Test Conditions	HYA060P04LQ2			Unit
			Min	Typ.	Max	
Dynamic Characteristics						
R _G	Gate Resistance	V _{GS} =0V, V _{DS} =0V, F=1.0MHz	-	4.7	-	
C _{iss}	Input Capacitance	V _{GS} =0V, V _{DS} =-25V, Frequency=1.0MHz	-	3524	-	pF
C _{oss}	Output Capacitance					
C _{rss}	Reverse Transfer Capacitance					
t _{d(ON)}	Turn-on Delay Time	V _{DD} =-20V, R _G =2.5 I _{DS} =-20A, V _{GS} =-10V	-	9.3	-	ns
T _r	Turn-on Rise Time					
t _{d(OFF)}	Turn-off Delay Time					
T _f	Turn-off Fall Time					
Gate Charge Characteristics						
Q _g	Total Gate Charge(V _{GS} =-10V)	V _{DS} =-32V, I _{DS} =-20A	-	87	-	nC
	Total Gate Charge(V _{GS} =-4.5V)			46		
Q _{gs}	Gate-Source Charge		-	11	-	
Q _{gd}	Gate-Drain Charge		-	28	-	
V _{plateau}	Gate plateau voltage		-	-3.1	-	V

Note: *Pulse test pulse width 300us duty cycle 2%

Typical Operating Characteristics

Figure 1: Power Dissipation

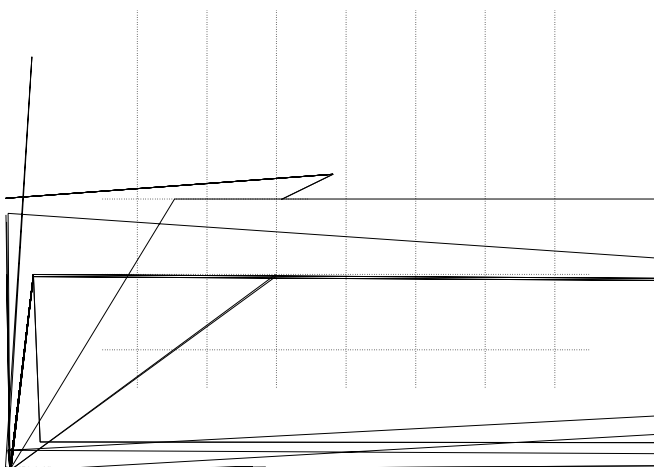


Figure 2: Drain Current

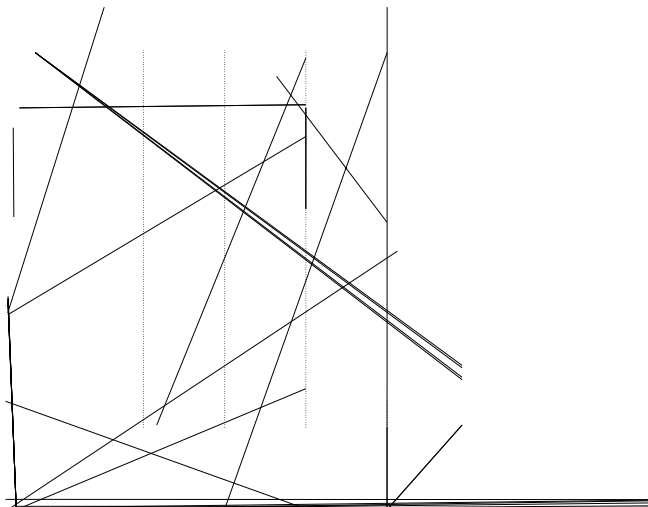


Figure 3: Safe Operation Area

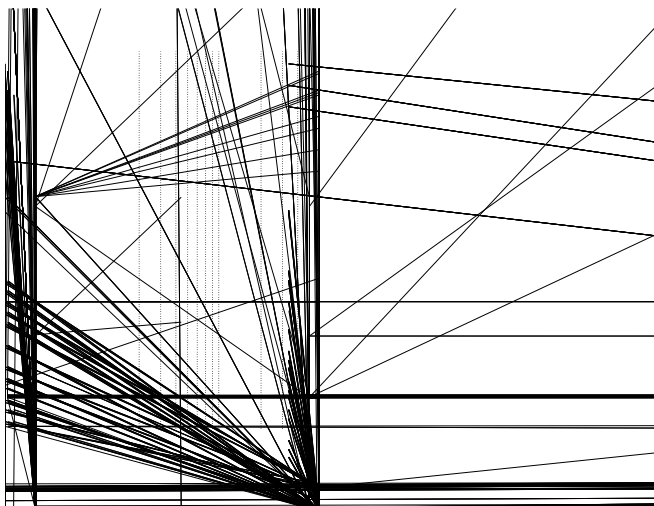


Figure 4: Thermal Transient Impedance

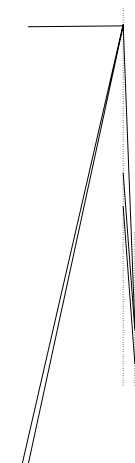


Figure 5: Output Characteristics

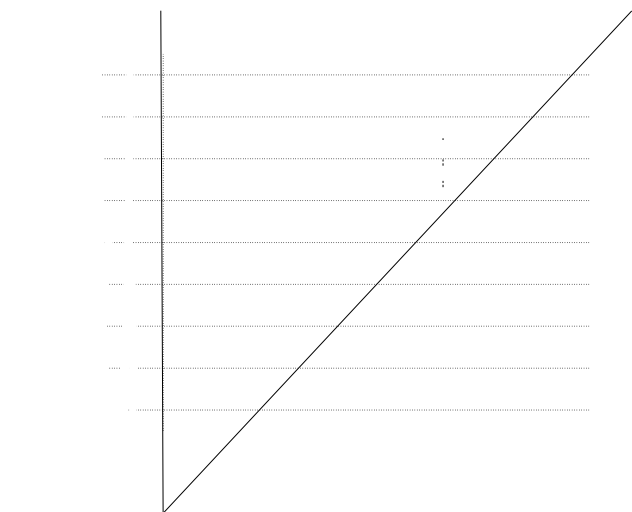


Figure 6: Drain-Source On Resistance



Typical Operating Characteristics(Cont.)

Figure 7: On-Resistance vs. Temperature

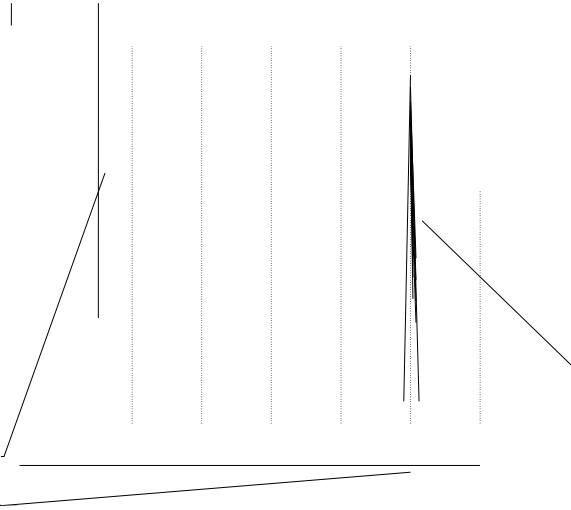


Figure 8: Source-Drain Diode Forward



Figure 9: Capacitance Characteristics

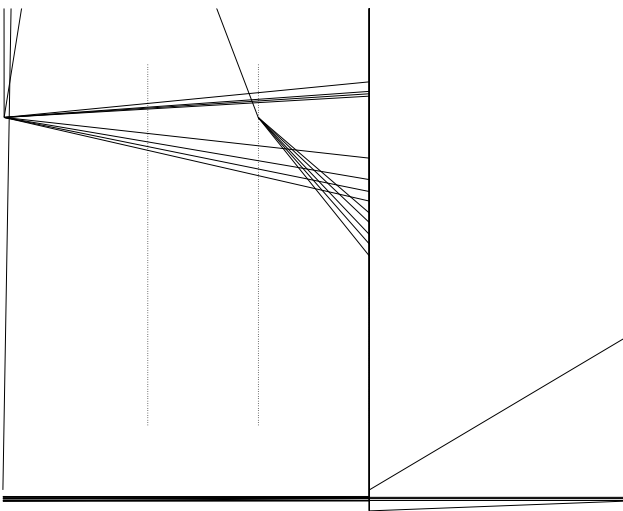


Figure 10: Gate Charge Characteristics

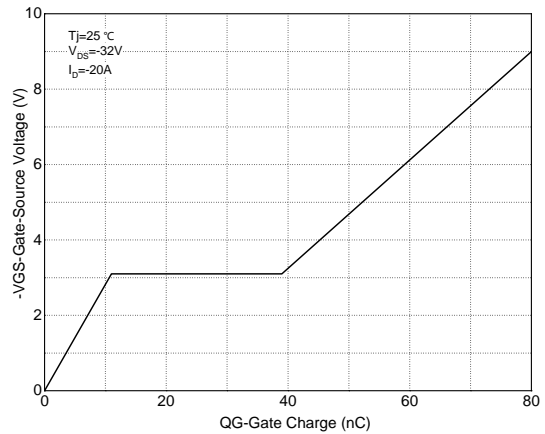


Figure 11: Transfer Characteristics

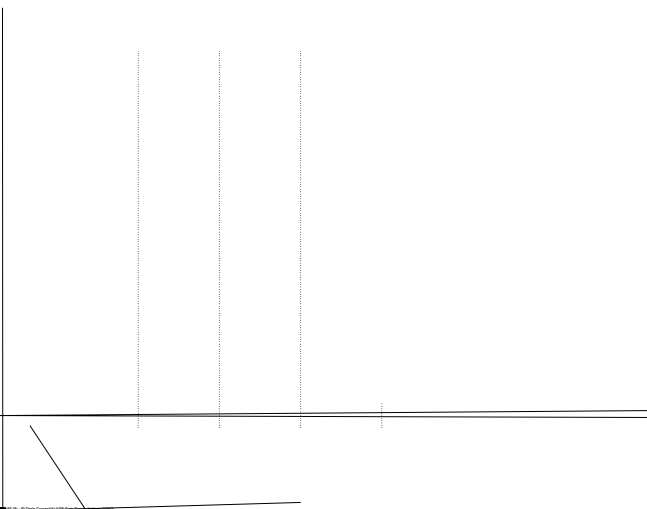
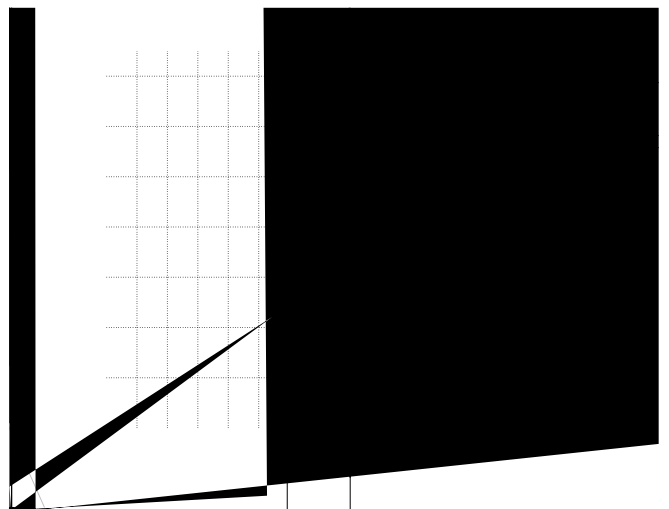


Figure 12: Gate Threshold Voltage



Typical Operating Characteristics(Cont.)

Figure 13: Drain-Source Breakdown

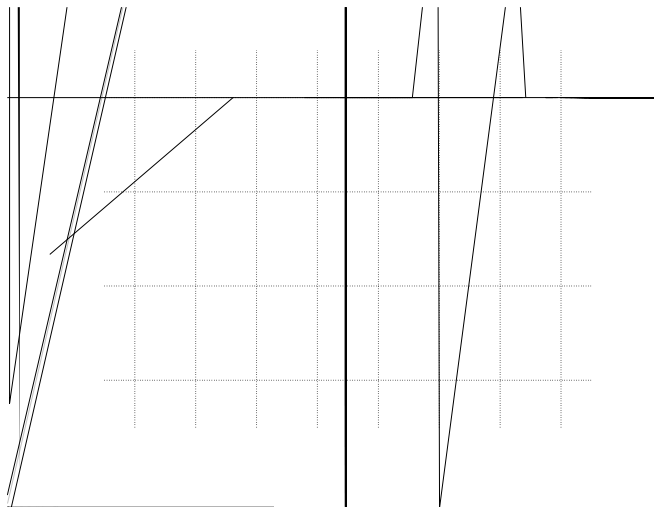


Figure 14: R_{dson} vs. Gate Voltage

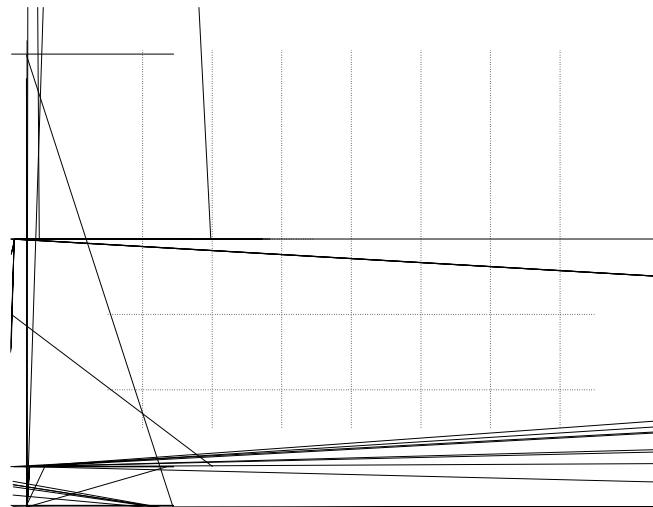
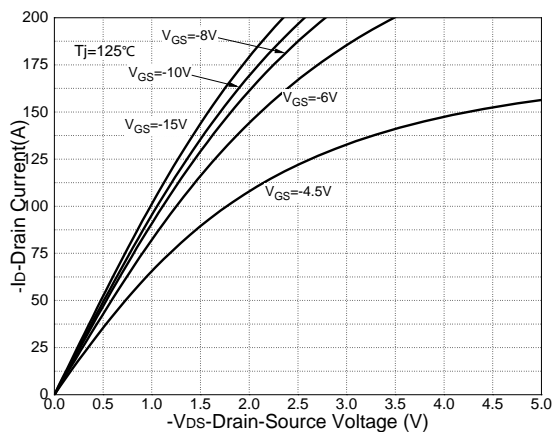
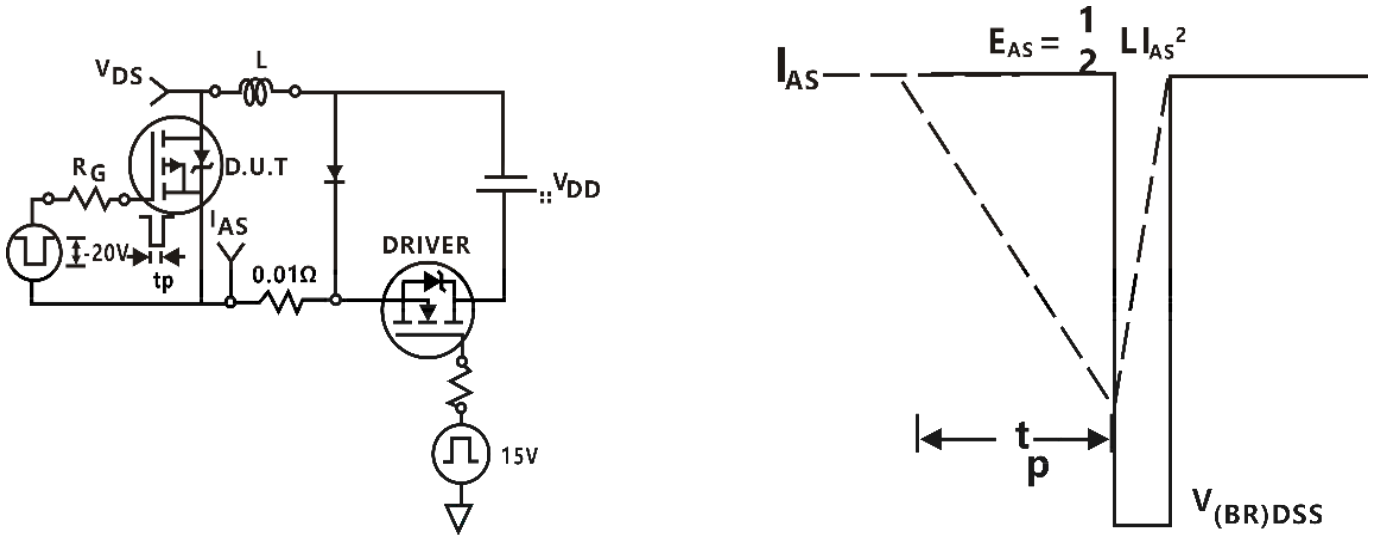


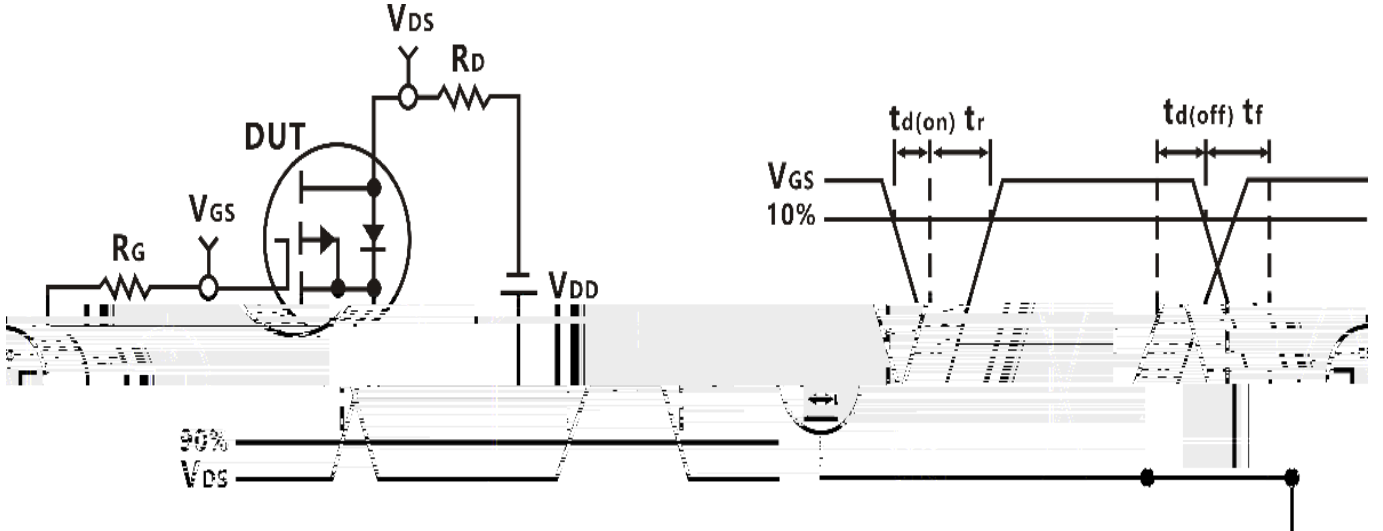
Figure 15: Output Characteristics 125



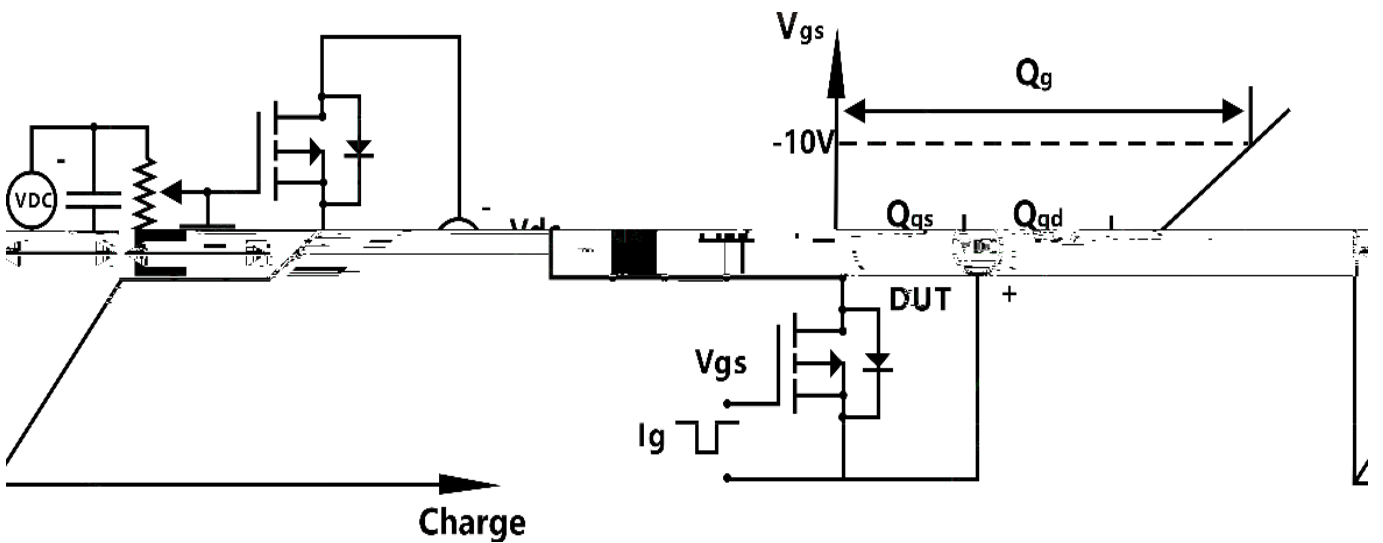
Avalanche Test Circuit



Switching Time Test Circuit



Gate Charge Test Circuit

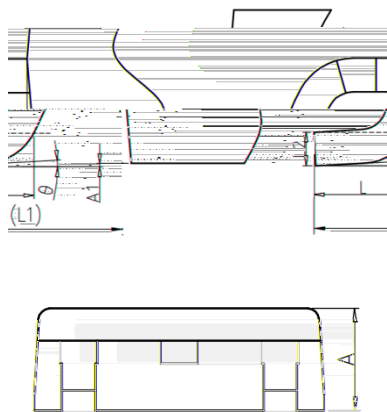
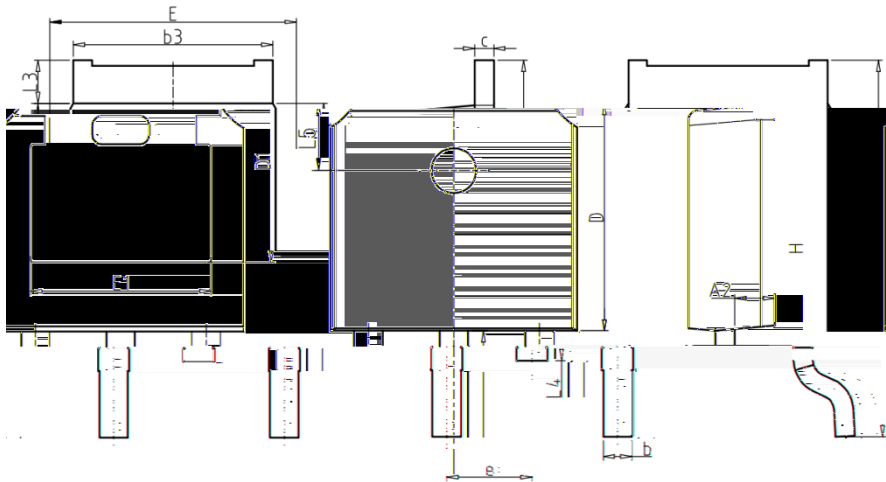


Device Per Unit

Package Type	Unit	Quantity
TO-252-2L	Tube	75
TO-252-2L	Reel	2500
TO-251-3L	Tube	75
TO-251-3S	Tube	75

Package Information

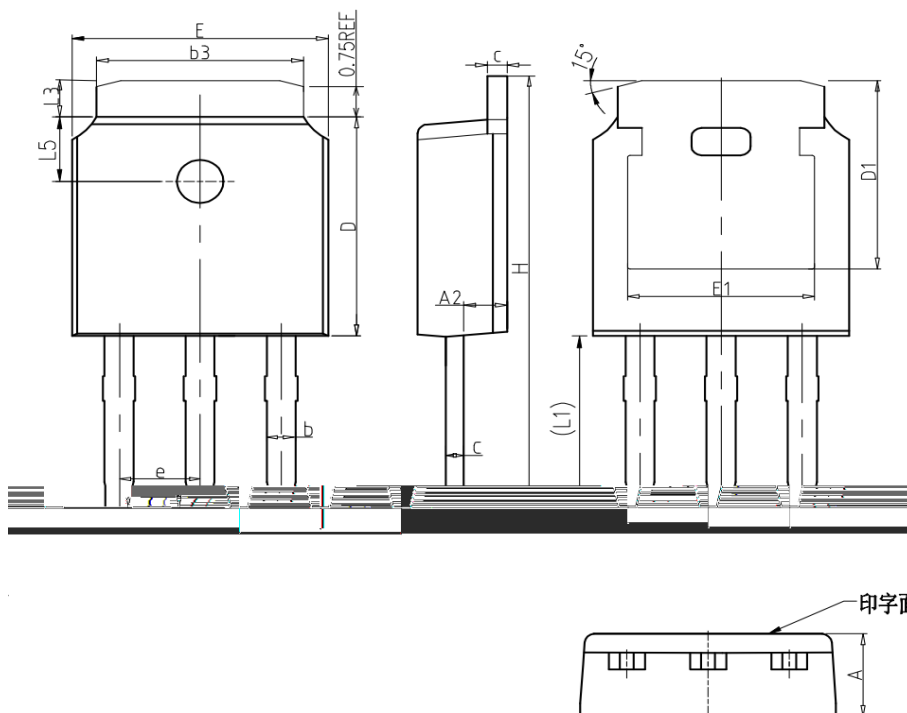
TO-252-2L



COMMON DIMENSIONS			
SYMBOL	mm		
	MIN	NOM	MAX
A	2.20	2.30	2.40
A1	0.00	-	0.20
A2	0.97	1.07	1.17
b	0.68	0.78	0.90
b3	5.20	5.33	5.50
c	0.43	0.53	0.63
D	5.98	6.10	6.22
D1	5.30REF		
E	6.40	6.60	6.80
E1	4.63	-	-
e	2.286BSC		
H	9.40	10.10	10.50
L	1.38	1.50	1.75
L1	2.90REF		
L2	0.51BSC		
L3	0.88	-	1.28
L4	-	-	1.00
L5	1.65	1.80	1.95
	0°	-	8°

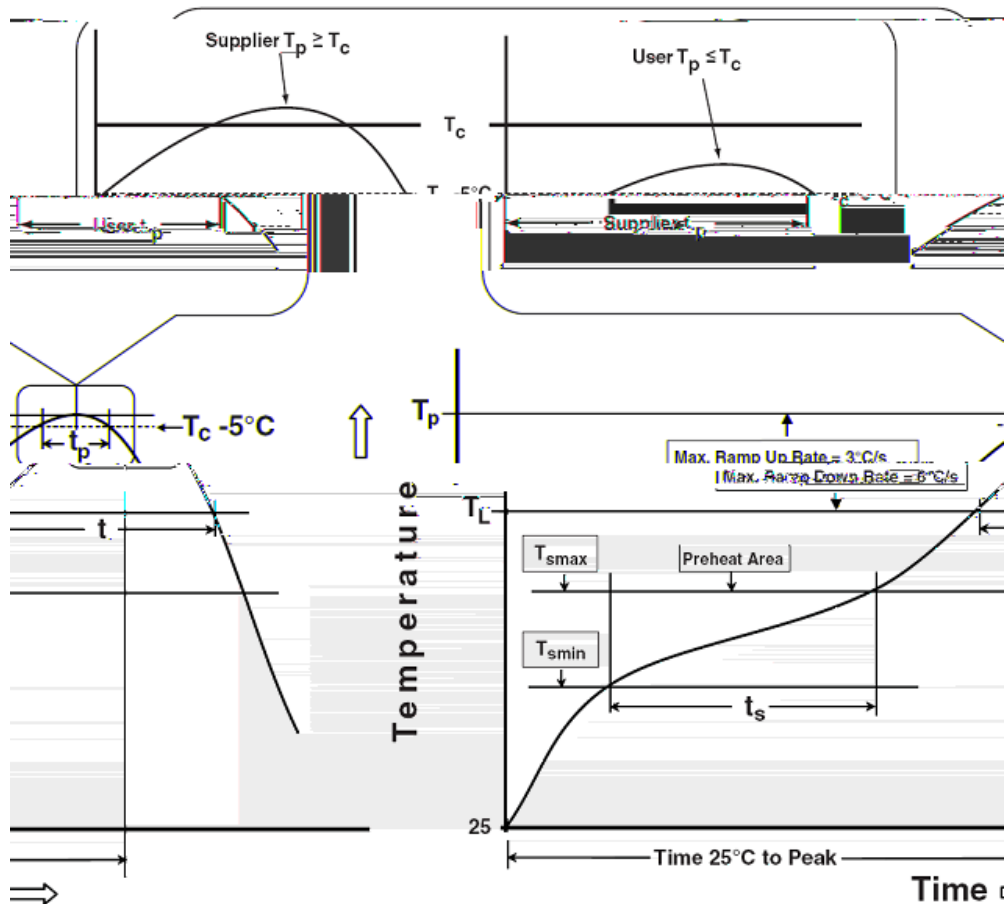
HYA060P04LQ2D/U/V

TO-251-3S



COMMON DIMENSIONS			
SYMBOL	mm		
	MIN	NOM	MAX
A	2.20	2.30	2.40
A2	0.97	1.07	1.17
b	0.68	0.78	0.90
b3	5.20	5.33	5.50
c	0.43	0.53	0.63
D	5.98	6.10	6.22
D1	5.30REF		
E	6.40	6.60	6.80
E1	4.63	-	-
e	2.286BSC		
H	10.00	11.22	11.44
L1	3.90	4.10	4.30
L3	0.88	1.02	1.28
L5	1.65	1.80	1.95

Classification Profile



Classification Reflow Profiles

Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Preheat & Soak		
Temperature min (T_{smin})	100 °C	150 °C
Temperature max (T_{smax})	150 °C	200 °C
Time (T_{smin} to T_{smax}) (t_s)	60-120 seconds	60-120 seconds
Average ramp-up rate (T_{smax} to T_p)	3 °C/second max.	3°C/second max.
Liquidous temperature (T_L)	183 °C	217 °C
Time at liquidous (t_L)	60-150 seconds	60-150 seconds
Peak package body Temperature (T_p)*	See Classification Temp in table 1	See Classification Temp in table 2
Time (t_p)** within 5°C of the specified classification temperature (T_c)	20** seconds	30** seconds
Average ramp-down rate (T_p to T_{smax})	6 °C/second max.	6 °C/second max.
Time 25°C to peak temperature	6 minutes max.	8 minutes max.

*Tolerance for peak profile Temperature (T_p) is defined as a supplier minimum and a user maximum.

** Tolerance for time at peak profile temperature (t_p) is defined as a supplier minimum and a user maximum.

Table 1.SnPb Eutectic Process Classification Temperatures (Tc)

Package Thickness	Volume mm ³	Volume mm ³
	<350	350
2.5 mm	235 °C	220 °C
	220 °C	220 °C

Table 2.Pb-free Process Classification Temperatures (Tc)

Package Thickness	Volume mm ³	Volume mm ³	Volume mm ³
	<350	350-2000	2000
<1.6 mm	260 °C	260 °C	260 °C
1.6 mm 2.5 mm	260 °C	250 °C	245 °C
2.5 mm	250 °C	245 °C	245 °C

Reliability Test Program

Test item	Method	Description
MSL	JESD22-A113	85°C/85%/168Hrs
RSH	JESD22- B106(PTH)	260± 5 10± 1S
PCT	JESD22-A102	121 ,100%RH, 96hours, 205KPa
TCT	JESD22-A104	1000 Cycles, -55°C~150°C
HTRB	JESD22-A108B	1000 Hrs, 100% BV _{DSS} @ 175
HTGB	JESD22-A108B	1000 Hrs, 100%V _{gs} @ 175
BHAST	JESD22-A110D	130 85%RH 230KPA;U=32V
IOL	MIL-STD-750	Ta=25 , Tj 100 , Ton/Toff 3.5min 8600cycles

Customer Service

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